

IN THE CLAIMS

Rewrite the pending elected claims as follows:

1. (Currently amended) A memory system comprising:
~~a memory controller connected to at least one channel;~~
~~memory devices connected to the at least one channel, wherein at least one of the~~
~~memory devices is a low bandwidth device being individually incapable of communicating a~~
~~first data block with the memory controller during a first time period;~~
~~wherein the memory controller is configured to communicate control information to~~
~~at least a first plurality of the memory devices via the at least one channel, and the first~~
~~plurality of memory devices, as a multiplexed group on the channel, are configured to~~
~~communicate a first data block between the memory controller and the first plurality of the~~
~~memory devices during the first time period in response to the control information.~~
at least one channel;
a plurality of memory devices coupled to at least the one channel,
wherein the plurality of memory devices includes at least a first memory device
having a first bandwidth and the first bandwidth is less than a first data block size divided by
a first time period; and
a memory controller coupled to at least the one channel,
wherein during one mode of operation the memory controller provides control
information to at least a first group of memory devices in the plurality of memory devices via
at least the one channel, the first group of memory devices including the first memory device,
and at least the first group of memory devices, as a multiplexed group, communicate a first
data block to the memory controller via at least the one channel during the first time period in
accordance with the control information.
2. (Currently amended) The memory system of claim 1, wherein each one of the first
~~group plurality of memory devices is configured to communicate contribute~~ a second data
block, which has a size less than the first data block size, to the first data block
~~communicated~~ during the first time period.
3. (Currently amended) The memory system of claim 2, ~~wherein the at least one channel~~
~~comprises including~~ two channels, each one of the two channels coupled to connecting a
second ~~group plurality of memory devices in the plurality of memory devices~~ to the memory
controller.

4. (Currently amended) The memory system of claim 3 wherein the second group plurality of memory devices comprises sixteen memory devices.
5. (Currently amended) The memory system of claim 2, ~~wherein the at least one channel comprises including~~ four full channels and one half channel, each one of the full channels coupled to connecting a second plurality group of memory devices in the plurality of memory devices, and the one half channel coupled to connecting half of the second group plurality of memory devices.
6. (Currently amended) The memory system of claim 5, wherein the second group plurality of memory devices comprises sixteen memory devices.
7. (Currently amended) The memory system of claim 2, ~~wherein the at least one channel comprises including~~ eight channels, each of the eight channels coupled to channel-connecting a second group plurality of memory devices in the plurality of memory devices.
8. (Currently amended) The memory system of claim 7, wherein the second group plurality of memory devices comprises eight memory devices.
9. (Currently amended) The memory system of claim 2, ~~wherein the at least one channel comprises including~~ four channels, each of the four channels coupled to channel-connecting a second group plurality of memory devices in the plurality of memory devices.
10. (Currently amended) The memory system of claim 9, wherein the second group plurality of memory devices comprises eight memory devices.
11. (Currently amended) A memory system comprising:
 - ~~a memory controller connected to at least one repeater via a main channel;~~
 - ~~wherein each repeater connects a first plurality of memory devices via at least one auxiliary channel, and wherein each one of the first plurality of memory devices is a low bandwidth device individually incapable of communicating a first data block with the memory controller during a first time period;~~
 - ~~wherein the memory controller is configured to communicate control information to the first plurality of the memory devices via the at least the main channel, the at least one repeater, and the at least one auxiliary channel, and the first plurality of memory devices, as a multiplexed group on the channel, are configured to communicate a first data block between the memory controller and the first plurality of the memory devices during the first time period in response to the control information.~~
 - a main channel;

at least one repeater coupled to the main channel;
at least one auxiliary channel coupled to at least the one repeater;
a first plurality of memory devices coupled to at least the one auxiliary channel,
wherein each one of the first plurality of memory devices has a bandwidth that is less
than a first data block size divided by a first time period; and
a memory controller coupled to the main channel,
wherein during one mode of operation the memory controller provides control
information to the first plurality of memory devices via the main channel, at least the one
repeater and at least the one auxiliary channel, and at least the first plurality of memory
devices, as a multiplexed group, communicate a first data block to the memory controller
during the first time period in accordance with the control information.

12. (Currently amended) The memory system of claim 11, wherein each memory device in the first plurality of memory devices communicates ~~contributes~~ a second data block, which has a size less than the first data block size, to the first data block transferred during the first time period.

13. (Currently amended) The memory system of claim 11, ~~wherein the~~ including a first auxiliary channel and a second auxiliary channel, and wherein at least the one repeater ~~connects~~ is coupled to a second plurality of memory devices via ~~[[a]]~~ the first auxiliary channel, and ~~connects~~ is coupled to a third plurality of memory devices via ~~[[a]]~~ the second auxiliary channel.

14. (Currently amended) The memory system of claim 13, wherein ~~each one of the~~ second plurality of memory devices and ~~the third pluralities~~ plurality of memory devices each comprise ~~comprises~~ eight memory devices.

15. (Withdrawn) A memory system capable of selectively operating in first and second modes, comprising:

a memory controller, memory devices, and a channel connecting the memory controller with the memory devices;

wherein each one of the memory devices is capable of operating in at least a first and a second power state, the first power state consuming more power than the second power state; such that

while the memory system is operating in the first mode, the memory controller is configured to generate a first power down device identification (ID) unique to one of the

memory devices, whereby the one memory device upon receiving the first power down device ID will transition from the first power state to the second power state; and

while the memory system is operating in the second mode, the memory controller generates a second power down device ID having the same structure as the first power down device ID, such that a plurality of memory devices upon receiving the second power down device ID transition from the first power state to a second power state.

16. (Withdrawn) A method of reading data in a memory system during a first time period, the memory system comprising a memory controller connected to memory devices via a data bus having multiple data bus lines, the method comprising:

communicating at least one command packet from the memory controller to a plurality of the memory devices;

for each memory device in the plurality of memory devices, seizing at least one data bus line during the first time period and returning data to the memory controller via the at least one data bus line in response to the at least one command packet.

17. (Withdrawn) The method of claim 16, wherein the first time period comprises a sequence of second time periods, and wherein each memory device in the plurality of memory devices seizes at least one data bus line during each one of the second time period.

18. (Withdrawn) The method of claim 17, wherein the data bus implements a wired OR function.